

View Online at <https://aerobasegroup.com/nsn/5961-01-322-4578>

Inclosure Material:

Metal all transistor

Overall Length:

1.252 inches all transistor

Overall Height:

0.340 inches all transistor

Overall Width:

0.700 inches all transistor

Mounting Facility Quantity:

2 all transistor

Internal Configuration:

Junction contact-darlington connected all transistor

Joint Electronic Device Engineering Council/jedec/case Outline Designation:

T0-66 all transistor

Internal Junction Configuration:

Npn all transistor

Component Function Relationship:

Matched

Component Name And Quantity:

2 transistor

Mounting Method:

Unthreaded hole all transistor

Features Provided:

Hermetically sealed case

Semiconductor Material:

Silicon all transistor

Voltage Rating In Volts Per Characteristic:

150.0 breakdown voltage, collector-to-emitter, base open all transistor

Current Rating Per Characteristic:

10.00 amperes source cutoff current all transistor

Power Rating Per Characteristic:

25.0 watts small-signal input power, common-collector absolute all transistor

Transfer Ratio:

1.0 static forward current transfer ratio, common-emitter all transistor and 10.0 static forward current transfer ratio, common-emitter all transistor

Maximum Operating Temperature Per Measurement Point:

175.0 degrees celsius junction all transistor

Terminal Type And Quantity:

2 pin all transistor and 1 case all transistor

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

Fig:

A110a0